

# Fault pruning:

Robust training of neural networks with memristive weights

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  - Main features: neuron-synapse structure, in-memory computation, learning capabilities



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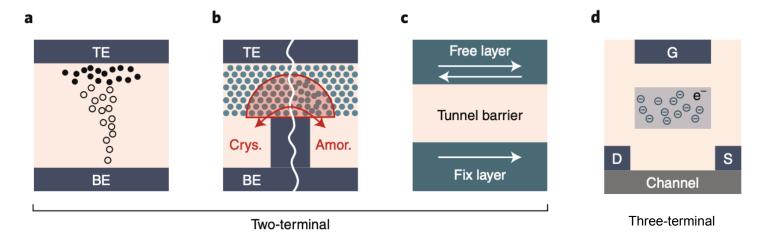


Image source:

Zhang, Wenqiang, et al. "Neuro-inspired computing chips." *Nature electronics* 3.7 (2020): 371-382.



- Key metrics for performance evaluation:
  - Computing density
  - Energy-efficiency
  - Computing accuracy: influenced by non-idealities of devices
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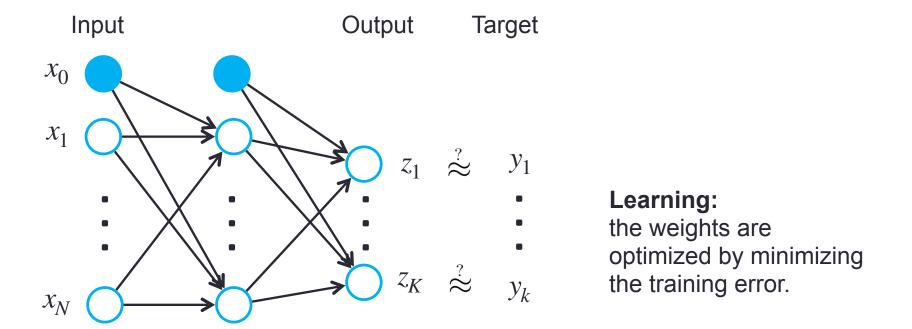
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#### Our focus:

- RRAM devices ("memristors")
- Improving energy-efficiency
- Learning "in-the-loop":
  - robust training of neural networks with memristive weights
  - detection of faulty memristors
  - improving computing accuracy



## Introduction: Neural networks

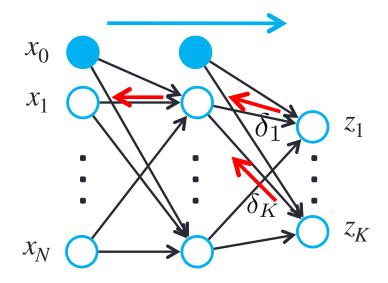


e.g., 
$$E = \frac{1}{2} \sum_{k=1}^{K} e_k^2 = \frac{1}{2} \sum_{k=1}^{K} (z_k - y_k)^2$$



## Introduction: Neural networks

- For learning, the gradient of the error function is needed.
  - Forward: Calculate activations and outputs of all neurons.
  - Backward: Calculate errors and propagate them back





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#### **Challenges:**

- Fabrication, operational constraints
- Limited endurance of the devices
- Yield and repeatability issues



## Memristive neural network training

### Faulty behavior of memristors

- Stuck memristors
- Faulty updates
  - Concordant switching faults
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#### Our approach:

- Analyze impact of faulty memristor behavior on neural network training
- Strategy: Use Fault pruning.
   Detection of faults during training and pruning of connections on the fly.



## Memristive weights

■ Mapping resistance  $R_i \in [R_{\min}, R_{\max}]$  to weight  $w_i \in [w_{\min}, w_{\max}]$ :

$$w_i = \alpha \left(\frac{1}{R_i} - \frac{1}{R_C}\right)$$



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Weight and resistance updates:

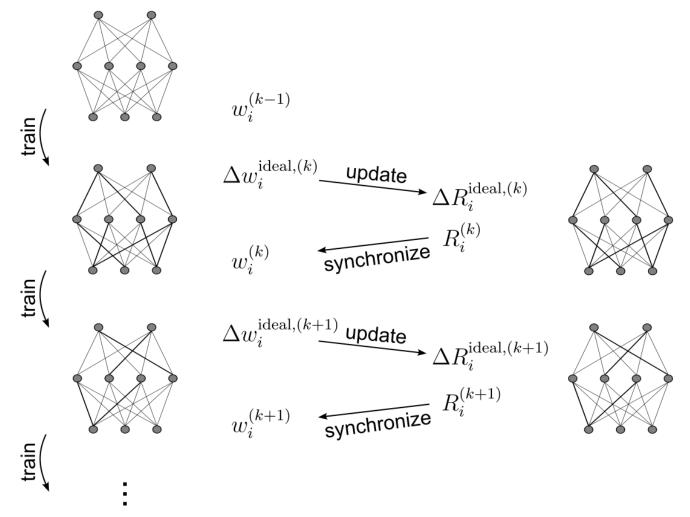
$$\Delta w_i = w_i^{(k)} - w_i^{(k-1)}$$
$$\Delta R_i = R_i^{(k)} - R_i^{(k-1)}$$



## In-the-loop training

High-precision network

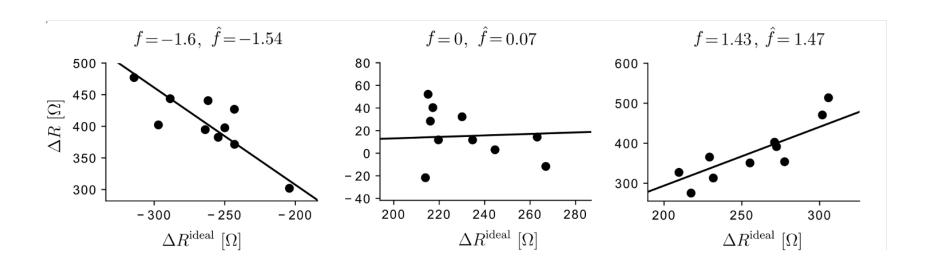
Memristive network





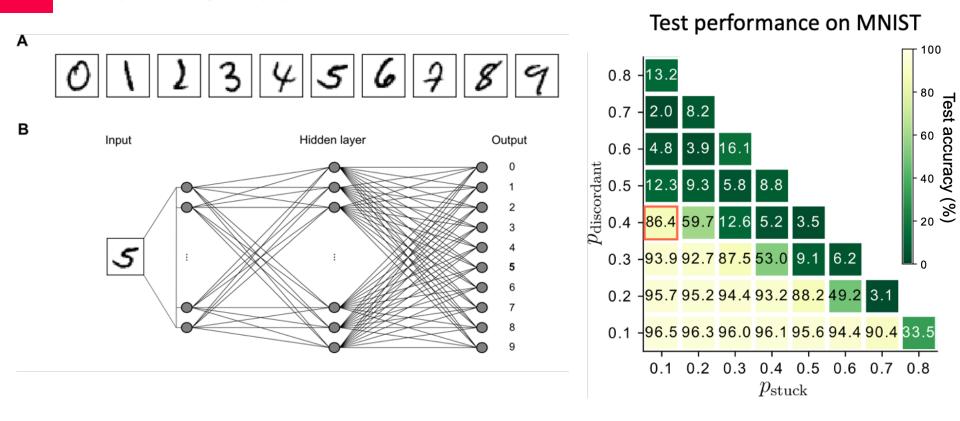
## Model of imperfect memristor

- Memristor faults modeled by fault factor  $f_i$ 
  - Modulates memristance change:  $\Delta R_i^{(k)} = f_i \cdot \Delta R_i^{\text{ideal, }(k)} + \eta_i^{(k)}$
  - Stuck memristors:  $f_i = 0$
  - Concordant changes:  $f_i > 0$
  - Discordant changes:  $f_i < 0$
  - Switching and readout noise  $\eta_i^{(k)}$  added.





## The MNIST task



Discordant memristive changes are detrimental.

Neural networks can be pruned significantly and achieve little loss in accuracy, hence we asked if one can prune faulty memristive connections.



## Fault pruning algorithm

Estimate fault factor over a window of previous updates:

$$\hat{f}_i = \frac{\sum_l \Delta R_i^{\text{ideal},(l)} \Delta R_i^{(l)}}{\sum_l \left(\Delta R_i^{\text{ideal},(l)}\right)^2}$$



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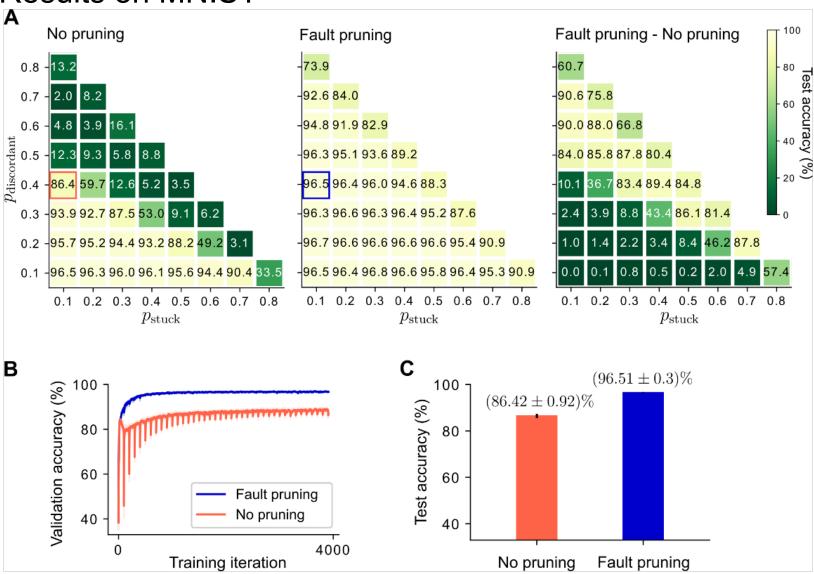
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- Remove detected unreliable memristors from the network if  $\hat{f}_i < \theta$ , and we set  $\theta = 0.1$
- Two variants of the algorithm
  - Variant 1: Prune faulty weights (set to zero)
  - Variant 2: Don't update faulty weights (keep last weight)

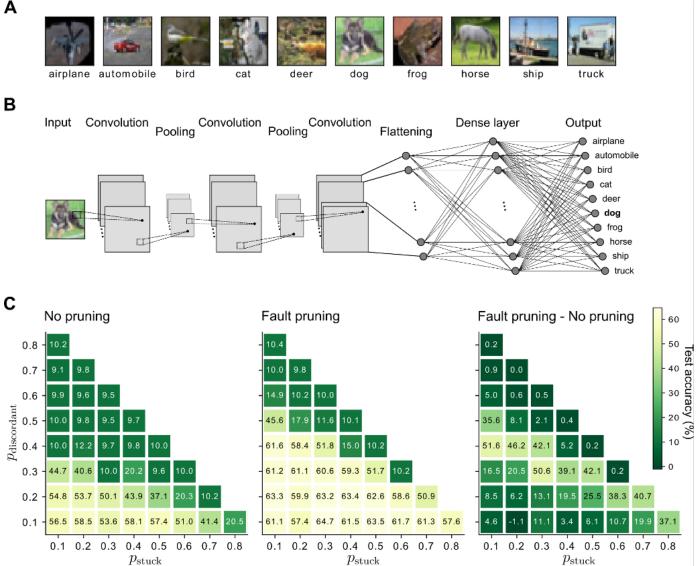


## Results on MNIST



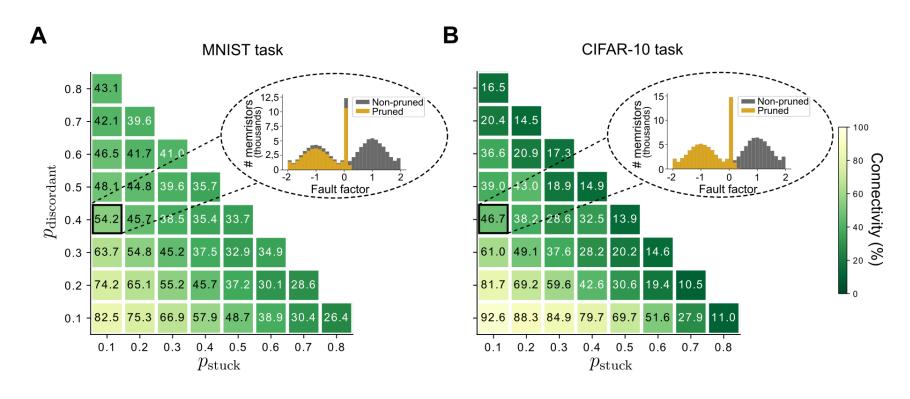


## Results on CIFAR-10





## Connectivity in the network after pruning





## **Summary and Conclusion**

- Fault pruning managed to preserve very good performance
- Estimation of faults on the fly, and acting accordingly
- General approach, independent of the network structure and trained tasks
- A simple linear regression to estimate faults
  - Can be substituted by more advanced approaches

#### Future work:

- Test the algorithm in a real-world scenario
- Handling memristors with discordant faults by adapting the requested update





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# Estimation of the fault factors $\hat{f}_i$

$$\Delta R_i = \hat{f}_i \cdot \Delta R_i^{\mathsf{ideal}} + \epsilon$$

Estimated from N=10 data points  $(\Delta R_i^{\mathsf{ideal},(l)}, \Delta R_i^{(l)}), \ l \in \{k-N+1, k-N+2, ..., k-1, k\}$ 

The least-squares estimator of  $\hat{f}_i$  minimises the error

$$\mathscr{L}(\hat{f}_i) := \sum_{l} \left( \Delta R_i^{(l)} - \hat{f}_i \cdot \Delta R_i^{\mathsf{ideal},(l)} \right)^2,$$

$$\frac{\partial \mathcal{L}}{\partial \hat{f}_i} = 2\sum_{l} \left( \Delta R_i^{(l)} - \hat{f}_i \cdot \Delta R_i^{\mathsf{ideal},(l)} \right) \left( -\Delta R_i^{\mathsf{ideal},(l)} \right) \stackrel{!}{=} 0$$

$$\hat{f}_i \sum_{l} \left( \Delta R_i^{\mathsf{ideal},(l)} \right)^2 = \sum_{l} \Delta R_i^{(l)} \Delta R_i^{\mathsf{ideal},(l)}$$

$$\hat{f}_i = \frac{\sum_l \Delta R_i^{(l)} \Delta R_i^{\mathsf{Ideal},(l)}}{\sum_l \left(\Delta R_i^{\mathsf{ideal},(l)}\right)^2}$$